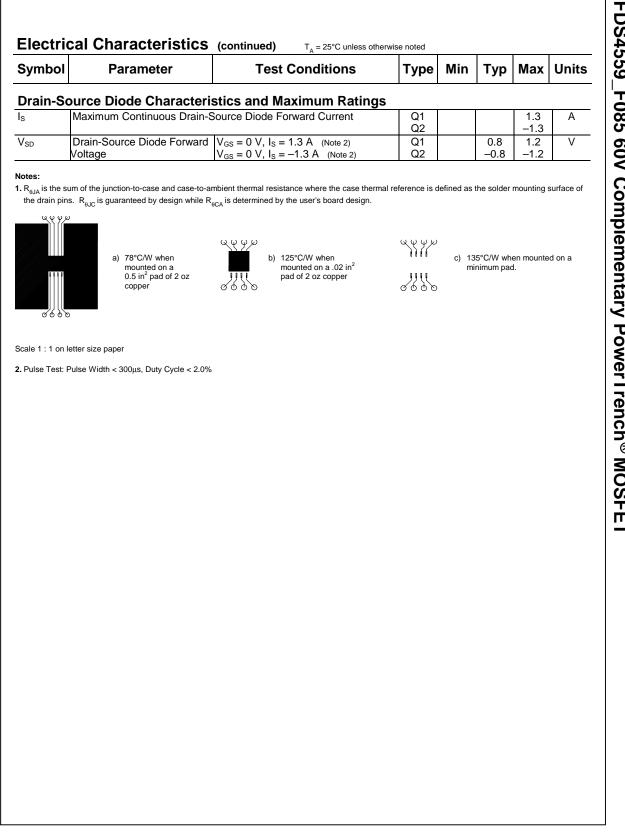


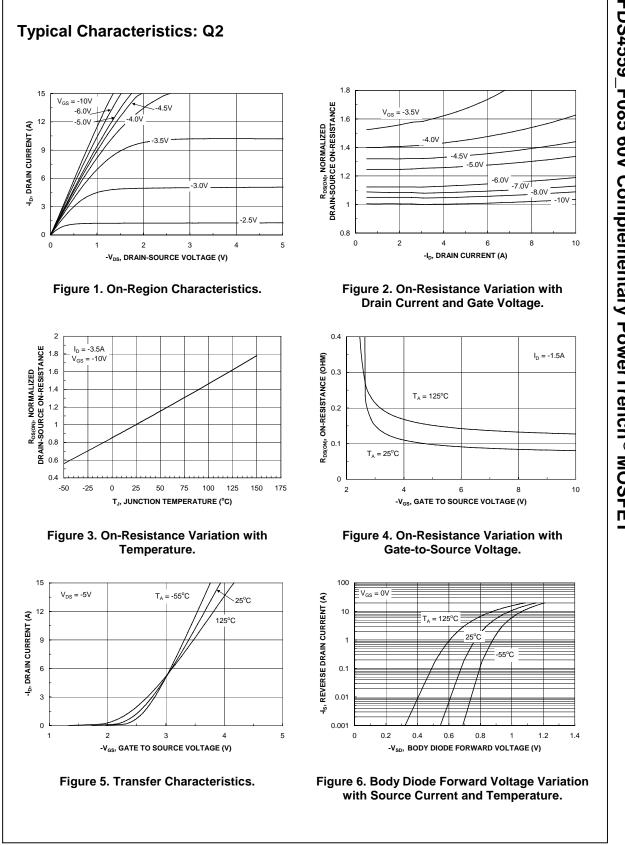
	Parameter				
V _{DSS}	Drain-Source Voltage		60	-60	V
V _{GSS}	Gate-Source Voltage		±20	±20	V
ID	Drain Current - Continuous	(Note 1a)	4.5	-3.5	А
	- Pulsed		20	-20	
PD	Power Dissipation for Dual Operation		2		W
	Power Dissipation for Single Operation	(Note 1a)	1.6		
	(Note 1b)		1.2		
		(Note 1c)		2	
T _J , T _{STG}	Operating and Storage Junction Tempera	ture Range	-55 to	o +150	°C
	Operating and Storage Junction Tempera AI Characteristics Thermal Resistance, Junction-to-Ambien	<u> </u>		o +150 78	°C/W
Therma	al Characteristics	<u> </u>	7		°C/V
Therma R _{θJA} R _{θJC} Packag	Al Characteristics Thermal Resistance, Junction-to-Ambien Thermal Resistance, Junction-to-Case Je Marking and Ordering Inf	(Note 1a) (Note 1)	7	78	

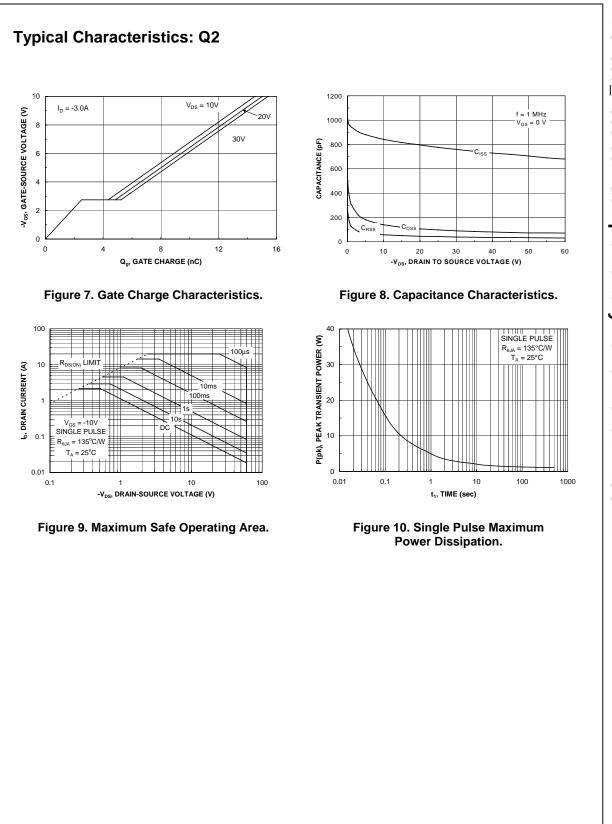
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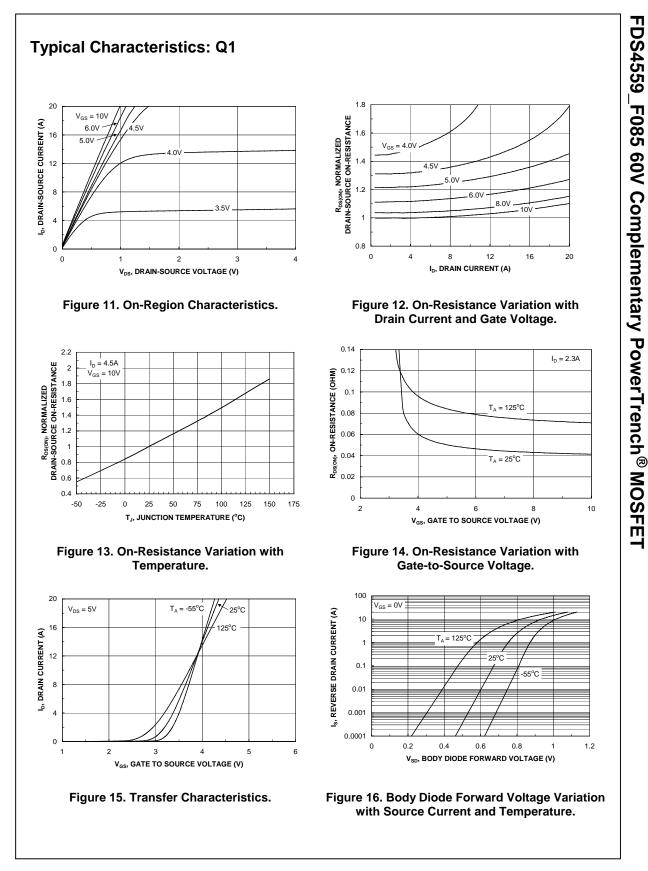
Symbol	Parameter	Test Conditions	Туре	Min	Тур	Max	Units
Drain-So	burce Avalanche Rating	IS (Note 1)					1
W _{DSS}	Single Pulse Drain-Source Avalanche Energy	$V_{DD} = 30 \text{ V}, \qquad I_D = 4.5 \text{ A}$	Q1			90	mJ
I _{AR}	Maximum Drain-Source Avalanche Current		Q1			4.5	A
Off Cha	racteristics	-	-				
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_D = 250 \mu A$ $V_{GS} = 0 V, I_D = -250 \mu A$	Q1 Q2	60 60			V
ΔBV_{DSS}	Breakdown Voltage	$I_D = 250 \ \mu A$, Referenced to $25^{\circ}C$	Q1		58		mV/°C
ΔΤ」	Temperature Coefficient	$I_D = -250 \mu$ A, Referenced to 25° C	Q2		-49		
DSS	Zero Gate Voltage Drain Current	$V_{DS} = 48 V, V_{GS} = 0 V$ $V_{DS} = -48 V, V_{GS} = 0 V$	Q1 Q2			1 -1	μA
I _{GSS}	Gate-Body Leakage	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$ $V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	Q1 Q2			<u>+</u> 100 +100	nA
On Cha	racteristics (Note 2)	• • • = •					•
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$ $V_{DS} = V_{GS}, I_D = -250 \ \mu A$	Q1 Q2	1 -1	2.2 -1.6	3 _3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, Referenced to 25°C $I_D = -250 \ \mu$ A, Referenced to 25°C	Q1 Q2		-5.5 4		mV/°C
R _{DS(on)}	Static Drain-Source On-Resistance		Q1		42 72 55	55 94 75	mΩ
		$ \begin{array}{l} V_{\rm GS} = -10 \ V, \ I_{\rm D} = -3.5 \ A \\ V_{\rm GS} = -10 \ V, \ I_{\rm D} = -3.5 \ A, \ T_{\rm J} = 125^{\circ}C \\ V_{\rm GS} = -4.5 \ V, \ I_{\rm D} = -3.1 \ A \end{array} $	Q2		82 130 105	105 190 135	
I _{D(on)}	On-State Drain Current	$V_{GS} = 10 V, V_{DS} = 5 V$ $V_{GS} = -10 V, V_{DS} = -5 V$	Q1 Q2	20 –20			A
g _{FS}	Forward Transconductance	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 4.5 \text{ A}$ $V_{DS} = -5 \text{ V}, \text{ I}_{D} = -3 \text{ 5 A}$	Q1 Q2		14 9		S
Dynami	c Characteristics						
Ciss	Input Capacitance	Q1	Q1		650 750		pF
Coss	Output Capacitance	$V_{DS} = 25 V, V_{GS} = 0 V,$ f = 1.0 MHz Q2	Q2 Q1 Q2		759 80 90		pF
C _{rss}	Reverse Transfer Capacitance	$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1.0 MHz	Q2 Q1 Q2		35 39		pF
Switchin	g Characteristics (Note 2		Q2		00		
	Turn-On Delay Time	Q1	Q1		11	20	ns
	Turn-On Rise Time	$V_{\text{DD}} = 30 \text{ V}, \text{ I}_{\text{D}} = 1 \text{ A},$ $V_{\text{GS}} = 10 \text{ V}, \text{ R}_{\text{GEN}} = 6 \Omega$	Q2 Q1		7 8	14 18	ns
d(off)	Turn-Off Delay Time		Q2 Q1		10 19	20 35	ns
•	Turn-Off Fall Time	$V_{DD} = -30 \text{ V}, \text{ I}_D = -1 \text{ A},$ $V_{GS} = -10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$	Q2 Q1		19 6	34 15	ns
y ^a .	Total Gate Charge	Q1	Q2 Q1 Q2		12 12.5	22 18 21	nC
Q _{gs}	Gate-Source Charge	V _{DS} = 30 V, I _D = 4.5 A, V _{GS} = 10 V Q2	Q2 Q1 Q2		15 2.4 2.5	21	nC
Q _{gd}	Gate-Drain Charge	$V_{DS} = -30$ V, $I_D = -3.5$ A, $V_{GS} = -10$ V	Q2 Q1 Q2		2.5 2.6 3.0		nC

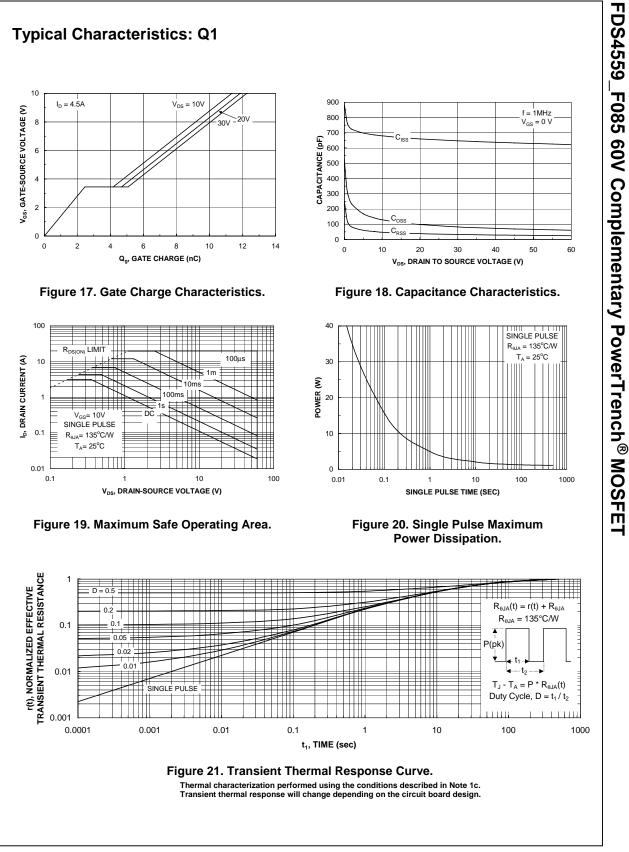
FDS4559_F085 60V Complementary PowerTrench[®] MOSFET

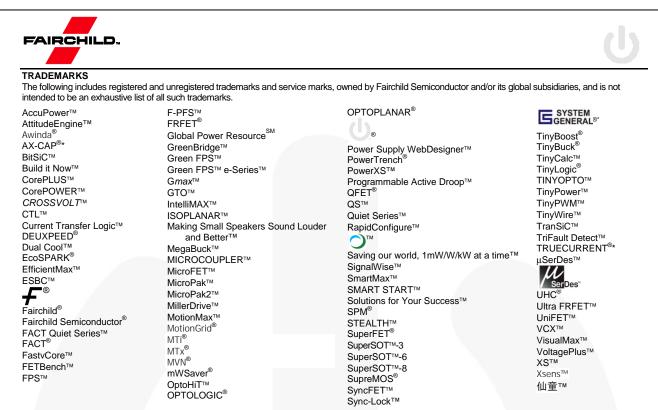












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